RS1AD THRU RS1MD

SURFACE MOUNT FAST RECOVERY RECTIFIERS

Reverse Voltage – 50 to 1000 V Forward Current – 1 A

Features

- · High current capability
- High surge current capability
- High reliability
- Low reverse current
- · Low forward voltage drop
- Fast switching for high efficiency

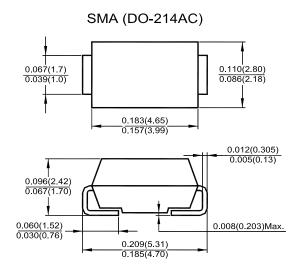
Mechanical Data

• Case: SMA (DO-214AC) molded plastic

• Mounting position: Any

• Lead: Lead formed for surface mount

• Polarity: Color band denotes cathode end



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20 %.

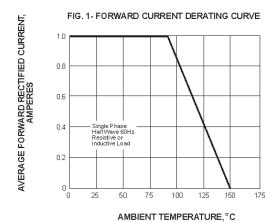
Parameter	Symbols	RS1AD	RS1BD	RS1DD	RS1GD	RS1JD	RS1KD	RS1MD	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current at T _a = 90 °C	I _{F(AV)}	1							Α
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	35						А	
Maximum Forward Voltage at I _F = 1 A	V _F	1.3							V
	I _R	5 50						μA	
Maximum Reverse Recovery Time 1)	t _{rr}	150			250	500		ns	
Typical Junction Capacitance 2)	C _j	50						pF	
Operating and Storage Temperature Range	T _j , T _{stg}	- 65 to + 150							°C

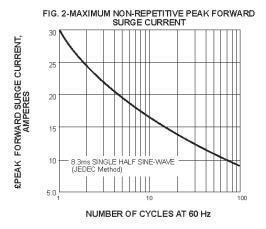
¹⁾ Reverse recovery test conditions $I_F = 0.5 \text{ A}$, $I_R = 1 \text{ A}$, $I_{rr} = 0.25 \text{ A}$.

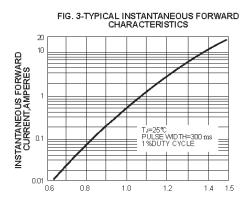


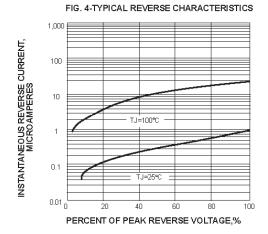


 $^{^{2)}\}mbox{Measured}$ at 1 MHz and applied reverse voltage of 4 V.

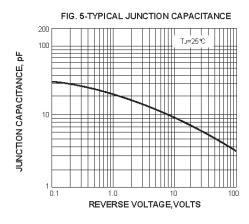


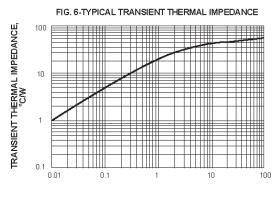












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